

25AA160A/B, 25LC160A/B

16K SPI[™] Bus Serial EEPROM

Device Selection Table

Part Number	Vcc Range	Page Size	Temp. Ranges	Packages
25LC160A	2.5-5.5V	16 Byte	I,E	P, SN, ST, MS
25AA160A	1.8-5.5V	16 Byte	I	P, SN, ST, MS
25LC160B	2.5-5.5V	32 Byte	I,E	P, SN, ST, MS
25AA160B	1.8-5.5V	32 Byte	I	P, SN, ST, MS

Features

- Max. clock 10 MHz
- · Low-power CMOS technology
- 2048 x 8-bit organization
- 16 byte page ('A' version devices)
- 32 byte page ('B' version devices)
- Write cycle time: 5 ms max.
- · Self-timed ERASE and WRITE cycles
- · Block write protection
- Protect none, 1/4, 1/2 or all of array
- · Built-in write protection
 - Power-on/off data protection circuitry
 - Write enable latch
 - Write-protect pin
- Sequential read
- High reliability
 - Endurance: 1,000,000 erase/write cycles
 - Data retention: > 200 years
 - ESD protection: > 4000V
- Temperature ranges supported;

-	Industrial (I):	-40°C to	+85°C
-	Automotive (E): -40°C to	+125°C

Pin Function Table

	i
Name	Function
CS	Chip Select Input
SO	Serial Data Output
WP	Write-Protect
Vss	Ground
SI	Serial Data Input
SCK	Serial Clock Input
HOLD	Hold Input
Vcc	Supply Voltage

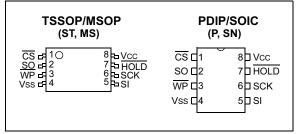
Description

The Microchip Technology Inc. 25AA160A/B, 25LC160A/B (25XX160A/B^{*}) are 16 Kbit Serial Electrically Erasable PROMs. The memory is accessed via a simple Serial Peripheral InterfaceTM (SPITM) compatible serial bus. The bus signals required are a clock input (SCK) plus separate data in (SI) and data out (SO) lines. Access to the device is controlled through a Chip Select (\overline{CS}) input.

Communication to the device can be paused via the hold pin (HOLD). While the device is paused, transitions on its inputs will be ignored, with the exception of chip select, allowing the host to service higher priority interrupts.

The 25XX160A/B is available in standard packages including 8-lead PDIP and SOIC, and advanced packaging including 8-lead MSOP, and 8-lead TSSOP. Pb-free (Pure Matte Sn) finish is also available.

Package Types (not to scale)



SPI is a registered trademark of Motorola Semiconductor.

*25XX160A/B is used in this document as a generic part number for the 25AA160A/B, 25LC160A/B devices.

1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings^(†)

Vcc	7.0V
All inputs and outputs w.r.t. Vss	-0.6V to Vcc +1.0V
Storage temperature	65°C to 150°C
Ambient temperature under bias	65°C to 125°C
ESD protection on all pins	4 kV

† NOTICE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for an extended period of time may affect device reliability.

TABLE 1-1: DC CHARACTERISTICS

DC CHARACTERISTICS			Industrial (I):TAMB = -40°C to $+85°C$ Vcc = 1.8V to 5.5VAutomotive (E):TAMB = -40°C to $+125°C$ Vcc = 2.5V to 5.5V				
Param. No.	Sym Characteristic		Min.	Max.	Units	Test Conditions	
D001	VIH1	High-level input	2.0	Vcc +1	V	Vcc ≥ 2.7V (Note)	
D002	VIH2	voltage	0.7 Vcc	Vcc +1	V	Vcc< 2.7V (Note)	
D003	VIL1	Low-level input	-0.3	0.8	V	Vcc ≥ 2.7V (Note)	
D004	VIL2	voltage	-0.3	0.2 Vcc	V	Vcc < 2.7V (Note)	
D005	Vol	Low-level output	—	0.4	V	IOL = 2.1 mA	
D006	Vol	voltage	—	0.2	V	IoL = 1.0 mA, Vcc < 2.5V	
D007	Voн	High-level output voltage	Vcc -0.5	—	V	ІОН = -400 μА	
D008	ILI	Input leakage current		±1	μΑ	CS = Vcc, VIN = Vss to Vcc	
D009	Ilo	Output leakage current		±1	μA	CS = Vcc, Vout = Vss to Vcc	
D010	CINT	Internal Capacitance (all inputs and outputs)	_	7	pF	Тамв = 25°С, CLK = 1.0 MHz, Vcc = 5.0V (Note)	
D011	ICC Read		_	6	mA	Vcc = 5.5V; FcLk = 10.0 MHz; SO = Open	
		Operating Current		2.5	mA	Vcc = 2.5V; FcLк = 5.0 MHz; SO = Open	
D012	ICC Write			3	mA	Vcc = 5.5V	
D013	Iccs	Standby Current	_	5	μA	\overline{CS} = Vcc = 5.5V, Inputs tied to Vcc or Vss, TAMB = -40°C TO +125°C	
				1	μA	CS= Vcc = 2.5V, Inputs tied to Vcc orVss, TAMB = -40°C TO +85°C	

Note: This parameter is periodically sampled and not 100% tested.

AC CHARACTERISTICS			Industrial (I): TAMB = -40° C to $+85^{\circ}$ C Vcc = 1.8 V to 5.5 V Automotive (E): TAMB = -40° C to $+125^{\circ}$ C Vcc = 2.5 V to 5.5 V				
Param. No. Sym. Characteristic		Characteristic	Min.	Max.	Units	Test Conditions	
1	Fclk	Clock Frequency		10 5 3	MHz MHz MHz	$4.5V \le Vcc \le 5.5V$ $2.5V \le Vcc < 4.5V$ $1.8V \le Vcc < 2.5V$	
2	Tcss	CS Setup Time	50 100 150		ns ns ns	$4.5V \le Vcc \le 5.5V$ $2.5V \le Vcc < 4.5V$ $1.8V \le Vcc < 2.5V$	
3	Тсѕн	CS Hold Time	100 200 250		ns ns ns	$4.5V \le Vcc \le 5.5V$ $2.5V \le Vcc < 4.5V$ $1.8V \le Vcc < 2.5V$	
4	TCSD	CS Disable Time	50	_	ns	_	
5	Tsu	Data Setup Time	10 20 30		ns ns ns	$4.5V \le Vcc \le 5.5V$ $2.5V \le Vcc < 4.5V$ $1.8V \le Vcc < 2.5V$	
6	Тно	Data Hold Time	20 40 50		ns ns ns	$4.5V \le Vcc \le 5.5V$ $2.5V \le Vcc < 4.5V$ $1.8V \le Vcc < 2.5V$	
7	TR	CLK Rise Time	_	500	ns	(Note 1)	
8	TF	CLK Fall Time	_	500	ns	(Note 1)	
9	Тні	Clock High Time	50 100 150		ns ns ns	$4.5V \le Vcc \le 5.5V$ $2.5V \le Vcc < 4.5V$ $1.8V \le Vcc < 2.5V$	
10	TLO	Clock Low Time	50 100 150		ns ns ns	$4.5V \le Vcc \le 5.5V$ $2.5V \le Vcc < 4.5V$ $1.8V \le Vcc < 2.5V$	
11	TCLD	Clock Delay Time	50		ns	—	
12	TCLE	Clock Enable Time	50	—	ns	—	
13	Τv	Output Valid from Clock Low		50 100 160	ns ns ns	$4.5V \le Vcc \le 5.5V$ $2.5V \le Vcc < 4.5V$ $1.8V \le Vcc < 2.5V$	
14	Тно	Output Hold Time	0	_	ns	(Note 1)	
15	TDIS	Output Disable Time		40 80 160	ns ns ns	4.5V ≤ Vcc ≤ 5.5V (Note 1) 2.5V ≤ Vcc ≤ 4.5V (Note 1) 1.8V ≤ Vcc ≤ 2.5V (Note 1)	
16	THS	HOLD Setup Time	20 40 80		ns ns ns	$\begin{array}{l} 4.5V \leq Vcc \leq 5.5V \\ 2.5V \leq Vcc < 4.5V \\ 1.8V \leq Vcc < 2.5V \end{array}$	

TABLE 1-2:AC CHARACTERISTICS

Note 1: This parameter is periodically sampled and not 100% tested.

- 2: This parameter is not tested but ensured by characterization. For endurance estimates in a specific application, please consult the Total Endurance[™] Model which can be obtained from our web site: www.microchip.com.
- **3:** Twc begins on the rising edge of \overline{CS} after a valid write sequence and ends when the internal write cycle is complete.

TABLE 1-2:	AC CHARACTERISTICS (CONTINUED)
------------	--------------------------------

AC CHARACTERISTICS			Industrial (I):TAMB = -40° C to $+85^{\circ}$ CVcc = 1.8 V to 5.5 VAutomotive (E):TAMB = -40° C to $+125^{\circ}$ CVcc = 2.5 V to 5.5 V				
Param. No. Sym. Characteristic			Min.	Max.	Units	Test Conditions	
17	Тнн	HOLD Hold Time	20 40 80		ns ns ns	$\begin{array}{l} 4.5V \leq Vcc \leq 5.5V \\ 2.5V \leq Vcc < 4.5V \\ 1.8V \leq Vcc < 2.5V \end{array}$	
18	Тнz	HOLD Low to Output High-Z	30 60 160		ns ns ns	4.5V ≤ Vcc ≤ 5.5V (Note 1) 2.5V ≤ Vcc < 4.5V (Note 1) 1.8V ≤ Vcc < 2.5V (Note 1)	
19	Тн∨	HOLD High to Output Valid	30 60 160		ns ns ns	$4.5V \le Vcc \le 5.5V$ $2.5V \le Vcc < 4.5V$ $1.8V \le Vcc < 2.5V$	
20	Twc	Internal Write Cycle Time	—	5	ms	(Nоте 3)	
21		Endurance	1M	—	E/W Cycles	(Nоте 2)	

Note 1: This parameter is periodically sampled and not 100% tested.

- 2: This parameter is not tested but ensured by characterization. For endurance estimates in a specific application, please consult the Total Endurance[™] Model which can be obtained from our web site: www.microchip.com.
- **3:** Twc begins on the rising edge of \overline{CS} after a valid write sequence and ends when the internal write cycle is complete.

TABLE 1-3:AC TEST CONDITIONS

AC Waveform:	
VLO = 0.2V	—
VHI = VCC - 0.2V	(Note 1)
VHI = 4.0V	(Note 2)
Timing Measurement Referenc	e Level
Input	0.5 Vcc
Output	0.5 Vcc

Note 1: For Vcc $\leq 4.0V$

2: For Vcc > 4.0V

FIGURE 1-1: HOLD TIMING

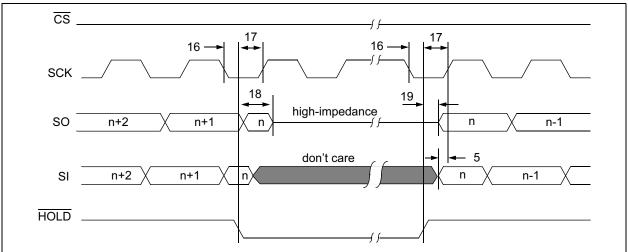


FIGURE 1-2: SERIAL INPUT TIMING

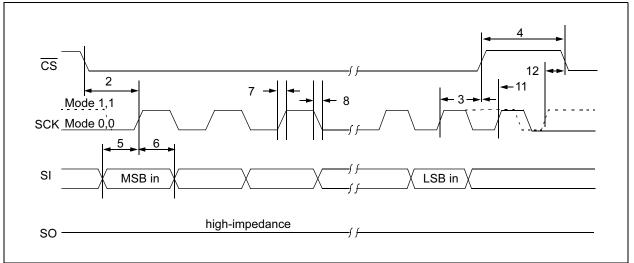
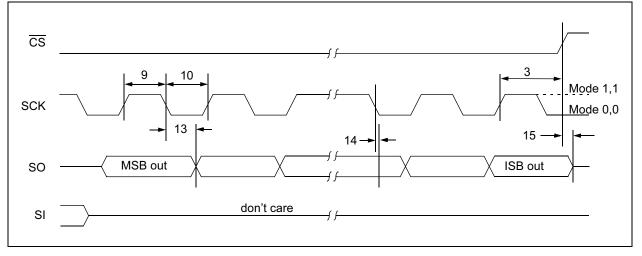


FIGURE 1-3: SERIAL OUTPUT TIMING



2.0 FUNCTIONAL DESCRIPTION

2.1 Principles of Operation

The 25XX160A/B are 2048 byte Serial EEPROMs designed to interface directly with the Serial Peripheral Interface (SPI) port of many of today's popular microcontroller families, including Microchip's PICmicro[®] microcontrollers. It may also interface with microcontrollers that do not have a built-in SPI port by using discrete I/O lines programmed properly with the software.

The 25XX160A/B contains an 8-bit instruction register. The device is accessed via the SI pin, with data being clocked in on the rising edge of SCK. The CS pin must be low and the HOLD pin must be high for the entire operation.

Table 2-1 contains a list of the possible instruction bytes and format for device operation. All instructions, addresses, and data are transferred MSB first, LSB last.

Data <u>(SI)</u> is sampled on the first rising edge of SCK after CS goes low. If the clock line is shared with other peripheral devices on the SPI bus, the user can assert the HOLD input and place the 25XX160A/B in 'HOLD' mode. After releasing the HOLD pin, operation will resume from the point when the HOLD was asserted.

2.2 Read Sequence

The device is selected by pulling \overline{CS} low. The 8-bit read instruction is transmitted to the 25XX160A/B followed by the 16-bit address, with the five MSBs of the address being don't care bits. After the correct read instruction and address are sent, the data stored in the memory at the selected address is shifted out on the SO pin. The data stored in the memory at the next address can be read sequentially by continuing to provide clock pulses. The internal address pointer is automatically incremented to the next higher address after each byte of data is shifted out. When the highest address is reached (07FFh), the address counter rolls over to address 0000h allowing the read cycle to be continued indefinitely. The read operation is terminated by raising the \overline{CS} pin (Figure 2-1).

2.3 Write Sequence

Prior to any attempt to write data to the 25XX160A/B, the write enable latch must be set by issuing the WREN instruction (Figure 2-4). This is done by setting CS low and then clocking out the proper instruction into the 25XX160A/B. After all eight bits of the instruction are transmitted, the CS must be brought high to set the write enable latch. If the write operation is initiated immediately after the WREN instruction without CS being brought high, the data will not be written to the array because the write enable latch will not have been properly set.

Once the write enable latch is set, the user may proceed by setting the \overline{CS} low, issuing a WRITE instruction, followed by the 16-bit address, with the five MSBs of the address being don't care bits, and then the data to be written. Up to 16 bytes (25XX160A) or 32 bytes (25XX160B) of data can be sent to the device before a write cycle is necessary. The only restriction is that all of the bytes must reside in the same page.

Note: Page write operations are limited to writing bytes within a single physical page, regardless of the number of bytes actually being written. Physical page boundaries start at addresses that are integer multiples of the page buffer size (or 'page size') and, end at addresses that are integer multiples of page size - 1. If a Page Write command attempts to write across a physical page boundary, the result is that the data wraps around to the beginning of the current page (overwriting data previously stored there), instead of being written to the next page as might be expected. It is therefore necessary for the application software to prevent page write operations that would attempt to cross a page boundary.

For the data to be actually written to the array, the \overline{CS} must be brought high after the Least Significant bit (D0) of the *n*th data byte has been clocked in. If \overline{CS} is brought high at any other time, the write operation will not be completed. Refer to Figure 2-2 and Figure 2-3 for more detailed illustrations on the byte write sequence and the page write sequence respectively. While the write is in progress, the Status Register may be read to check the status of the WPEN, WIP, WEL, BP1 and BP0 bits (Figure 2-6). A read attempt of a memory array location will not be possible during a write cycle. When the write cycle is completed, the write enable latch is reset.

25XX160A/B

Block Diagram

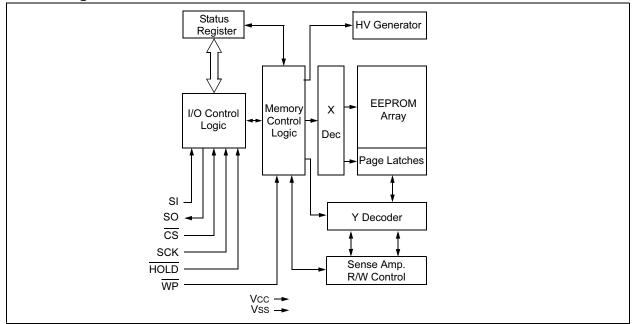
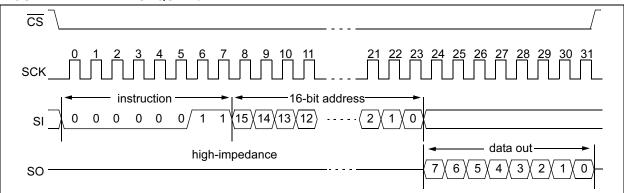


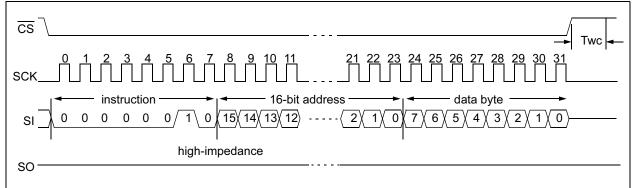
TABLE 2-1: INSTRUCTION SET

Instruction Name	Instruction Format	Description
READ	0000 0011	Read data from memory array beginning at selected address
WRITE	0000 0010	Write data to memory array beginning at selected address
WRDI	0000 0100	Reset the write enable latch (disable write operations)
WREN	0000 0110	Set the write enable latch (enable write operations)
RDSR	0000 0101	Read Status Register
WRSR	0000 0001	Write Status Register

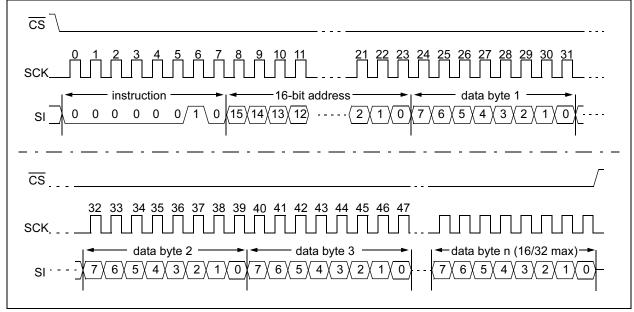












2.4 Write Enable (WREN) and Write Disable (WRDI)

The 25XX160A/B contains a write enable latch. See Table 2-4 for the Write-Protect Functionality Matrix. This latch must be set before any write operation will be completed internally. The WREN instruction will set the latch, and the WRDI will reset the latch.

The following is a list of conditions under which the write enable latch will be reset:

- Power-up
- + WRDI instruction successfully executed
- WRSR instruction successfully executed
- WRITE instruction successfully executed



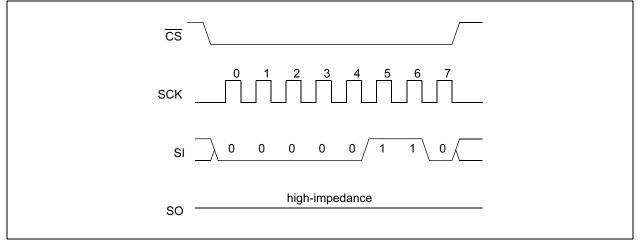
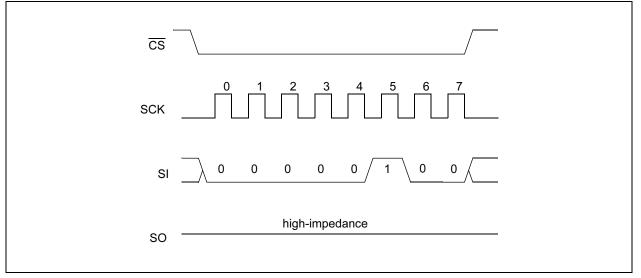


FIGURE 2-5: WRITE DISABLE SEQUENCE (WRDI)



2.5 Read Status Register Instruction (RDSR)

The Read Status Register instruction (RDSR) provides access to the Status Register. The Status Register may be read at any time, even during a write cycle. The Status Register is formatted as follows:

TABLE 2-2:	STATUS REGISTER

7	6	5	4	3	2	1	0	
W/R	I	I	I	W/R	W/R	R	R	
WPEN X X X BP1 BP0 WEL WIP								
W/R = w	W/R = writable/readable. R = read-only.							

The **Write-In-Process (WIP)** bit indicates whether the 25XX160A/B is busy with a write operation. When set to a '1', a write is in progress, when set to a '0', no write is in progress. This bit is read-only.

The **Write Enable Latch (WEL)** bit indicates the status of the write enable latch and is read-only. When set to a '1', the latch allows writes to the array, when set to a '0', the latch prohibits writes to the array. The state of this bit can always be updated via the WREN or WRDI commands regardless of the state of write protection on the Status Register. These commands are shown in Figure 2-4 and Figure 2-5.

The **Block Protection (BP0 and BP1)** bits indicate which blocks are currently write-protected. These bits are set by the user issuing the WRSR instruction. These bits are nonvolatile, and are shown in Table 2-3.

See Figure 2-6 for the RDSR timing sequence.

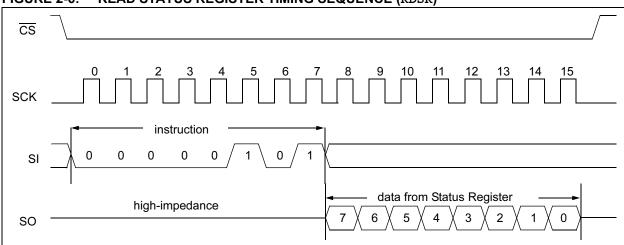


FIGURE 2-6: READ STATUS REGISTER TIMING SEQUENCE (RDSR)

2.6 Write Status Register Instruction (WRSR)

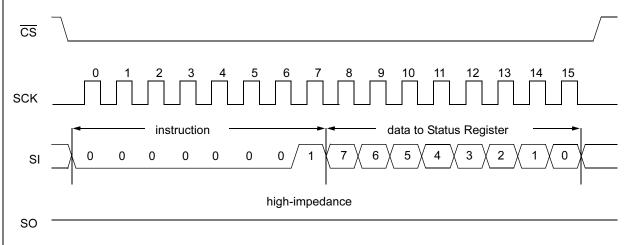
The Write Status Register instruction (WRSR) allows the user to write to the nonvolatile bits in the Status Register as shown in Table 2-2. The user is able to select one of four levels of protection for the array by writing to the appropriate bits in the Status Register. The array is divided up into four segments. The user has the ability to write-protect none, one, two or all four of the segments of the array. The partitioning is controlled as shown in Table 2-3.

The Write-Protect Enable (WPEN) bit is a nonvolatile bit that is available as an enable bit for the WP pin. The Write-Protect (WP) pin and the Write-Protect Enable (WPEN) bit in the Status Register control the programmable hardware write-protect feature. Hardware write protection is enabled when WP pin is low and the WPEN bit is high. Hardware write protection is disabled when either the WP pin is high or the WPEN bit is low. When the chip is hardware write-protected, only writes to nonvolatile bits in the Status Register are disabled. See Table 2-4 for a matrix of functionality on the WPEN bit. See Figure 2-7 for the WRSR timing sequence.

TABLE 2-3:ARRAY PROTECTION

BP1	BP0	Array Addresses Write-Protected
0	0	none
0	1	upper 1/4 (0600h - 07FFh)
1	0	upper 1/2 (0400h - 07FFh)
1	1	all (0000h - 07FFh)





2.7 Data Protection

The following protection has been implemented to prevent inadvertent writes to the array:

- The write enable latch is reset on power-up
- A write enable instruction must be issued to set the write enable latch
- After a byte write, page write or Status Register write, the write enable latch is reset
- CS must be set high after the proper number of clock cycles to start an internal write cycle
- Access to the array during an internal write cycle is ignored and programming is continued

2.8 Power-On State

The 25XX160A/B powers on in the following state:

- The device is in low-power Standby mode $(\overline{CS} = 1)$
- · The write enable latch is reset
- SO is in high-impedance state
- A high-to-low-level transition on CS is required to enter active state

TABLE 2-4: WRITE-PROTECT FUNCTIONALITY MATRIX

WEL (SR bit 1)	WPEN (SR bit 7)	WP (pin 3)	Protected Blocks	Unprotected Blocks	Status Register
0	х	х	Protected	Protected	Protected
1	0	х	Protected	Writable	Writable
1	1	0 (low)	Protected	Writable	Protected
1	1	1 (high)	Protected	Writable	Writable

x = don't care

3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1.

Name	Pin Number	Function
CS	1	Chip Select Input
SO	2	Serial Data Output
WP	3	Write-Protect Pin
Vss	4	Ground
SI	5	Serial Data Input
SCK	6	Serial Clock Input
HOLD	7	Hold Input
Vcc	8	Supply Voltage

3.1 Chip Select (CS)

A low level on this pin selects the device. A high level deselects the device and forces it into Standby mode. However, a programming cycle which is already initiated or in progress will be completed, regardless of the \overline{CS} input signal. If \overline{CS} is brought high during a program cycle, the device will go into Standby mode as soon as the programming cycle is complete. When the device is deselected, SO goes to the high-impedance state, allowing multiple parts to share the same SPI bus. A low-to-high transition on \overline{CS} after a valid write sequence initiates an internal write cycle. After power-up, a low level on \overline{CS} is required prior to any sequence being initiated.

3.2 Serial Output (SO)

The SO pin is used to transfer data out of the 25XX160A/B. During a read cycle, data is shifted out on this pin after the falling edge of the serial clock.

3.3 Write-Protect (WP)

This pin is used in conjunction with the WPEN bit in the Status Register to prohibit writes to the nonvolatile bits in the Status Register. When WP is low and WPEN is high, writing to the nonvolatile bits in the Status Register is disabled. All other operations function normally. When WP is high, all functions, including writes to the nonvolatile bits in the Status Register operate normally. If the WPEN bit is set, WP low during a Status Register write sequence will disable writing to the Status Register. If an internal write cycle has already begun, WP going low will have no effect on the write.

The $\overline{\text{WP}}$ pin function is blocked when the WPEN bit in the Status Register is low. This allows the user to install the 25XX160A/B in a system with $\overline{\text{WP}}$ pin grounded and still be able to write to the Status Register. The $\overline{\text{WP}}$ pin functions will be enabled when the WPEN bit is set high.

3.4 Serial Input (SI)

The SI pin is used to transfer data into the device. It receives instructions, addresses and data. Data is latched on the rising edge of the serial clock.

3.5 Serial Clock (SCK)

The SCK is used to synchronize the communication between a master and the 25XX160A/B. Instructions, addresses or data present on the SI pin are latched on the rising edge of the clock input, while data on the SO pin is updated after the falling edge of the clock input.

3.6 Hold (HOLD)

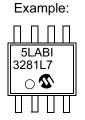
The HOLD pin is used to suspend transmission to the 25XX160A/B while in the middle of a serial sequence without having to retransmit the entire sequence again. It must be held high any time this function is not being used. Once the device is selected and a serial sequence is underway, the HOLD pin may be pulled low to pause further serial communication without resetting the serial sequence. The HOLD pin must be brought low while SCK is low, otherwise the HOLD function will not be invoked until the next SCK high-tolow transition. The 25XX160A/B must remain selected during this sequence. The SI, SCK and SO pins are in a high impedance state during the time the device is paused and transitions on these pins will be ignored. To resume serial communication, HOLD must be brought high while the SCK pin is low, otherwise serial communication will not resume. Lowering the HOLD line at any time will tri-state the SO line.

4.0 **PACKAGING INFORMATION**

4.1 **Package Marking Information**

8-Lead MSOP (150 mil)





Example:

<u>п п п п</u>

25LC160B

10328

Example:

25LC160B

I/SN 0328

S ^{1L7}

I/P 1L7

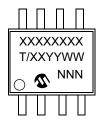
 \cap

MSOP 1st Line Marking Codes					
Device	std mark	Pb-free mark			
25AA160A	5AAA	G5AAA			
25AA160B	5AAB	G5AAB			
25LC160A	5LAA	G5LAA			
25LC160B	5LAB	G5LAB			

8-Lead PDIP

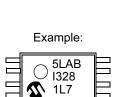


8-Lead SOIC



8-Lead TSSOP

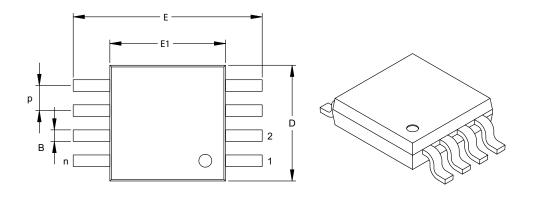


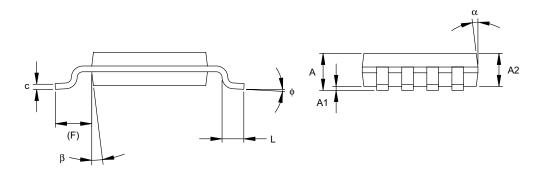


TSSOP 1st Line Marking Codes				
Device	std mark	Pb-free mark		
25AA160A	5AAA	NAAA		
25AA160B	5AAB	NAAB		
25LC160A	5LAA	NLAA		
25LC160B	5LAB	NLAB		

Legen	d: XXX T Blank YY WW NNN	Part number Temperature (I, E) Commercial Year code (last 2 digits of calendar year) except TSSOP and MSOP which use only the last 1 digit Week code (week of January 1 is week '01') Alphanumeric traceability code
Note:	Custom ma	arking available.

8-Lead Plastic Micro Small Outline Package (MS) (MSOP)





		INCHES			MILLIMETERS*		
nits	MIN	NOM	MAX	MIN	NOM	MAX	
n		8			8		
р		.026 BSC			0.65 BSC		
Α	-	-	.043	-	-	1.10	
A2	.030	.033	.037	0.75	0.85	0.95	
A1	.000	-	.006	0.00	-	0.15	
E		.193 TYP.			4.90 BSC		
E1		.118 BSC			3.00 BSC		
D		.118 BSC			3.00 BSC		
L	.016	.024	.031	0.40	0.60	0.80	
F		.037 REF			0.95 REF		
¢	0°	-	8°	0°	-	8°	
С	.003	.006	.009	0.08	-	0.23	
В	.009	.012	.016	0.22	-	0.40	
α	5°	-	15°	5°	-	15°	
β	5°	-	15°	5°	-	15°	
	n p A A2 A1 E E1 D L F φ c B α	n p A - A2 .030 A1 .000 E E1 D L .016 F φ 0° c .003 B .009 α 5°	n 8 P .026 BSC A - A2 .030 A1 .000 E .193 TYP. E1 .118 BSC D .118 BSC L .016 .024 F .037 REF φ 0° - c .003 .006 B .009 .012 α 5° -	n 8 P .026 BSC A - .043 A2 .030 .033 .037 A1 .000 - .006 E .193 TYP. .006 .024 D .118 BSC .031 .031 F .037 REF .037 REF .037 REF φ 0° - .8° c .003 .006 .009 B .009 .012 .016 α 5° - .15°	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	n 8 8 P .026 BSC 0.65 BSC A - .043 - A2 .030 .033 .037 0.75 0.85 A1 .000 - .006 0.00 - E .193 TYP. 4.90 BSC 3.00 BSC E1 .118 BSC 3.00 BSC D .118 BSC 3.00 BSC L .016 .024 .031 0.40 0.60 F .037 REF 0.95 REF 0.95 REF 0.95 REF ϕ 0° - 8° 0° - C .003 .006 .009 0.08 - B .009 .012 .016 0.22 - α 5° - 15° 5° -	

*Controlling Parameter

Notes:

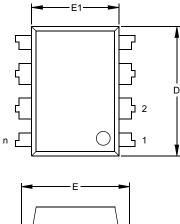
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

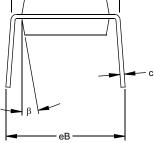
JEDEC Equivalent: MO-187

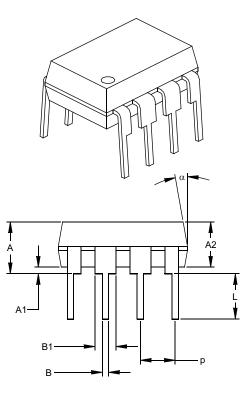
Drawing No. C04-111

25XX160A/B

8-Lead Plastic Dual In-line (P) – 300 mil (PDIP)





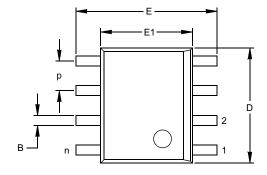


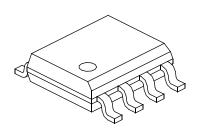
	Units		INCHES*		Ν	IILLIMETERS	6
Dimensi	on Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.100			2.54	
Top to Seating Plane	А	.140	.155	.170	3.56	3.94	4.32
Molded Package Thickness	A2	.115	.130	.145	2.92	3.30	3.68
Base to Seating Plane	A1	.015			0.38		
Shoulder to Shoulder Width	E	.300	.313	.325	7.62	7.94	8.26
Molded Package Width	E1	.240	.250	.260	6.10	6.35	6.60
Overall Length	D	.360	.373	.385	9.14	9.46	9.78
Tip to Seating Plane	L	.125	.130	.135	3.18	3.30	3.43
Lead Thickness	С	.008	.012	.015	0.20	0.29	0.38
Upper Lead Width	B1	.045	.058	.070	1.14	1.46	1.78
Lower Lead Width	В	.014	.018	.022	0.36	0.46	0.56
Overall Row Spacing	§ eB	.310	.370	.430	7.87	9.40	10.92
Mold Draft Angle Top	α	5	10	15	5	10	15
Mold Draft Angle Bottom	β	5	10	15	5	10	15

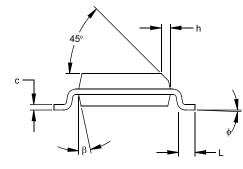
* Controlling Parameter § Significant Characteristic

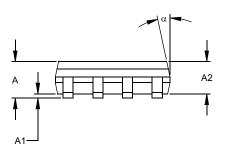
Notes: Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side. JEDEC Equivalent: MS-001 Drawing No. C04-018

8-Lead Plastic Small Outline (SN) – Narrow, 150 mil (SOIC)









		INCHES*			MILLIMETERS		
Dimensio	n Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.050			1.27	
Overall Height	Α	.053	.061	.069	1.35	1.55	1.75
Molded Package Thickness	A2	.052	.056	.061	1.32	1.42	1.55
Standoff §	A1	.004	.007	.010	0.10	0.18	0.25
Overall Width	Е	.228	.237	.244	5.79	6.02	6.20
Molded Package Width	E1	.146	.154	.157	3.71	3.91	3.99
Overall Length	D	.189	.193	.197	4.80	4.90	5.00
Chamfer Distance	h	.010	.015	.020	0.25	0.38	0.51
Foot Length	L	.019	.025	.030	0.48	0.62	0.76
Foot Angle	ø	0	4	8	0	4	8
Lead Thickness	С	.008	.009	.010	0.20	0.23	0.25
Lead Width	В	.013	.017	.020	0.33	0.42	0.51
Mold Draft Angle Top	α	0	12	15	0	12	15
Mold Draft Angle Bottom	β	0	12	15	0	12	15

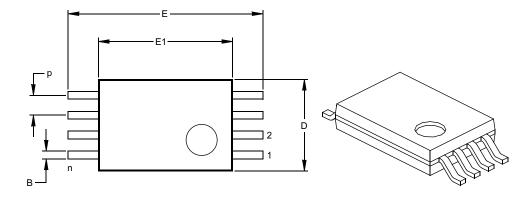
* Controlling Parameter § Significant Characteristic

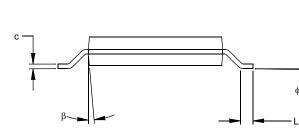
Notes:

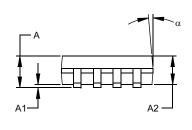
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side. JEDEC Equivalent: MS-012 Drawing No. C04-057

25XX160A/B

8-Lead Plastic Thin Shrink Small Outline (ST) – 4.4 mm (TSSOP)







Units			INCHES		MILLIMETERS*		
Dimensio	n Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.026			0.65	
Overall Height	Α			.043			1.10
Molded Package Thickness	A2	.033	.035	.037	0.85	0.90	0.95
Standoff §	A1	.002	.004	.006	0.05	0.10	0.15
Overall Width	Е	.246	.251	.256	6.25	6.38	6.50
Molded Package Width	E1	.169	.173	.177	4.30	4.40	4.50
Molded Package Length	D	.114	.118	.122	2.90	3.00	3.10
Foot Length	L	.020	.024	.028	0.50	0.60	0.70
Foot Angle	ø	0	4	8	0	4	8
Lead Thickness	С	.004	.006	.008	0.09	0.15	0.20
Lead Width	В	.007	.010	.012	0.19	0.25	0.30
Mold Draft Angle Top	α	0	5	10	0	5	10
Mold Draft Angle Bottom	β	0	5	10	0	5	10

* Controlling Parameter

§ Significant Characteristic

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .005" (0.127mm) per side. JEDEC Equivalent: MO-153 Drawing No. C04-086

ON-LINE SUPPORT

Microchip provides on-line support on the Microchip World Wide Web site.

The web site is used by Microchip as a means to make files and information easily available to customers. To view the site, the user must have access to the Internet and a web browser, such as Netscape[®] or Microsoft[®] Internet Explorer. Files are also available for FTP download from our FTP site.

Connecting to the Microchip Internet Web Site

The Microchip web site is available at the following URL:

www.microchip.com

The file transfer site is available by using an FTP service to connect to:

ftp://ftp.microchip.com

The web site and file transfer site provide a variety of services. Users may download files for the latest Development Tools, Data Sheets, Application Notes, User's Guides, Articles and Sample Programs. A variety of Microchip specific business information is also available, including listings of Microchip sales offices, distributors and factory representatives. Other data available for consideration is:

- Latest Microchip Press Releases
- Technical Support Section with Frequently Asked
 Questions
- Design Tips
- Device Errata
- Job Postings
- Microchip Consultant Program Member Listing
- Links to other useful web sites related to Microchip Products
- Conferences for products, Development Systems, technical information and more
- · Listing of seminars and events

SYSTEMS INFORMATION AND UPGRADE HOT LINE

The Systems Information and Upgrade Line provides system users a listing of the latest versions of all of Microchip's development systems software products. Plus, this line provides information on how customers can receive the most current upgrade kits. The Hot Line Numbers are:

1-800-755-2345 for U.S. and most of Canada, and

1-480-792-7302 for the rest of the world.

042003

READER RESPONSE

It is our intention to provide you with the best documentation possible to ensure successful use of your Microchip product. If you wish to provide your comments on organization, clarity, subject matter, and ways in which our documentation can better serve you, please FAX your comments to the Technical Publications Manager at (480) 792-4150.

Please list the following information, and use this outline to provide us with your comments about this document.

To:	Technical Publications Manager	Total Pages Sent
RE:	Reader Response	
From	n: Name	
	Company	
	Address	<u> </u>
	Telephone: ()	FAX: ()
Appl	ication (optional):	
Wou	ld you like a reply?YN	
Devi	ce: 25AA160A/B, 25LC160A/B	Literature Number: DS21807B
Ques	stions:	
1. \	What are the best features of this do	cument?
_		
- 2	How does this document meet your h	nardware and software development needs?
2. 1		
-		
3. [Do you find the organization of this d	ocument easy to follow? If not, why?
-		
_		
4. \	What additions to the document do y	ou think would enhance the structure and subject?
-		
5. \	what deletions from the document co	ould be made without affecting the overall usefulness?
-		
6. I	s there any incorrect or misleading in	nformation (what and where)?
_		
_		
7. H	How would you improve this docume	nt?
-		
_		

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.	2	<u>(</u>	– <u>X</u>	<u>/xx</u>	X	E	xamples:
Device	Tape &	Ree	I Temp Range	Package	Lead Finish	a) b)	Serial EEPROM, Industrial temp., MSOP package
Device	25AA1 25AA1 25LC1 25LC1	60B 60A	16 Kbit, 1.8V, 16 Byt 16 Kbit, 1.8V, 32 Byt 16 Kbit, 2.5V, 16 Byt 16 Kbit, 2.5V, 32 Byt	te Page SPI Ser te Page SPI Ser	ial EEPROM ial EEPROM	c)	Serial EEPROM, Industrial temp., TSSOP package, Pb-free 25AA160AT-I/SN = 16 Kbit, 16-byte page, 1.8V Serial EEPROM, Industrial temp., Tape & Reel, SOIC package
Tape & Reel	Blank T	= =	Standard packaging Tape & Reel			d)	25LC160A-I/MSG = 16 Kbit, 16-byte page, 2.5V Serial EEPROM, Industrial temp., MSOP package, Pb-free
Temperature Range	I E	= =	-40°C to+85°C -40°C to+125°C			e) f)	25LC160BT-I/SN = 16 Kbit, 32-byte page, 2.5V Serial EEPROM, Industrial temp., Tape & Reel, SOIC package 25LC160BT-I/ST = 16 Kbit, 32-byte page, 2.5V
Package	MS P SN ST	= = =	Plastic MSOP (Micro Plastic DIP (300 mil Plastic SOIC (150 m TSSOP, 8-lead	body), 8-lead '	, 8-lead		Serial EEPROM, Industrial temp., Tape & Reel, TSSOP package
Lead Finish	Blank G	=	Standard 63% / 37% Matte Tin (Pure Sn)	5 Sn/Pb			

Sales and Support

Data Sheets

Products supported by a preliminary Data Sheet may have an errata sheet describing minor operational differences and recommended workarounds. To determine if an errata sheet exists for a particular device, please contact one of the following:

- 1. Your local Microchip sales office
- 2. The Microchip Corporate Literature Center U.S. FAX: (480) 792-7277
- 3. The Microchip Worldwide Site (www.microchip.com)

Please specify which device, revision of silicon and Data Sheet (include Literature #) you are using.

New Customer Notification System

Register on our web site (www.microchip.com/cn) to receive the most current information on our products.

25XX160A/B

NOTES:

Note the following details of the code protection feature on Microchip devices:

- Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as "unbreakable."

Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.

Information contained in this publication regarding device applications and the like is intended through suggestion only and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. No representation or warranty is given and no liability is assumed by Microchip Technology Incorporated with respect to the accuracy or use of such information, or infringement of patents or other intellectual property rights arising from such use or otherwise. Use of Microchip's products as critical components in life support systems is not authorized except with express written approval by Microchip. No licenses are conveyed, implicitly or otherwise, under any intellectual property rights.

Trademarks

The Microchip name and logo, the Microchip logo, Accuron, dsPIC, KEELOQ, MPLAB, PIC, PICmicro, PICSTART,

PRO MATE and PowerSmart are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

AmpLab, FilterLab, microID, MXDEV, MXLAB, PICMASTER, SEEVAL and The Embedded Control Solutions Company are registered trademarks of Microchip Technology Incorporated in the U.S.A.

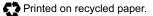
Application Maestro, dsPICDEM, dsPICDEM.net, ECAN, ECONOMONITOR, FanSense, FlexROM, fuzzyLAB,

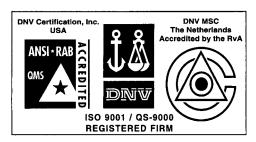
In-Circuit Serial Programming, ICSP, ICEPIC, microPort, Migratable Memory, MPASM, MPLIB, MPLINK, MPSIM, PICkit, PICDEM, PICDEM.net, PowerCal, PowerInfo, PowerMate, PowerTool, rfLAB, rfPIC, Select Mode, SmartSensor, SmartShunt, SmartTel and Total Endurance are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

Serialized Quick Turn Programming (SQTP) is a service mark of Microchip Technology Incorporated in the U.S.A.

All other trademarks mentioned herein are property of their respective companies.

© 2003, Microchip Technology Incorporated, Printed in the U.S.A., All Rights Reserved.





Microchip received QS-9000 quality system certification for its worldwide headquarters, design and wafer fabrication facilities in Chandler and Tempe, Arizona in July 1999 and Mountain View, California in March 2002. The Company's quality system processes and procedures are QS-9000 compliant for its PICmicro® 8-bit MCUs, KEELoo® code hopping devices, Serial EEPROMs, microperipherals, non-volatile memory and analog products. In addition, Microchip's quality system for the design and manufacture of development systems is ISO 9001 certified.



WORLDWIDE SALES AND SERVICE

AMERICAS

Corporate Office

2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 480-792-7200 Fax: 480-792-7277 Technical Support: 480-792-7627 Web Address: http://www.microchip.com

Atlanta

3780 Mansell Road, Suite 130 Alpharetta, GA 30022 Tel: 770-640-0034 Fax: 770-640-0307

Boston 2 Lan Drive, Suite 120 Westford, MA 01886

Tel: 978-692-3848 Fax: 978-692-3821 Chicago

333 Pierce Road, Suite 180 Itasca, IL 60143 Tel: 630-285-0071 Fax: 630-285-0075

Dallas

4570 Westgrove Drive, Suite 160 Addison, TX 75001 Tel: 972-818-7423 Fax: 972-818-2924

Detroit

Tri-Atria Office Building 32255 Northwestern Highway, Suite 190 Farmington Hills, MI 48334 Tel: 248-538-2250 Fax: 248-538-2260

Kokomo 2767 S. Albright Road Kokomo, IN 46902 Tel: 765-864-8360 Fax: 765-864-8387

Los Angeles

18201 Von Karman, Suite 1090 Irvine, CA 92612 Tel: 949-263-1888 Fax: 949-263-1338

Phoenix

2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 480-792-7966 Fax: 480-792-4338

San Jose

Microchip Technology Inc. 2107 North First Street, Suite 590 San Jose, CA 95131 Tel: 408-436-7950 Fax: 408-436-7955

Toronto

6285 Northam Drive, Suite 108 Mississauga, Ontario L4V 1X5, Canada Tel: 905-673-0699 Fax: 905-673-6509

ASIA/PACIFIC

Australia

Microchip Technology Australia Pty Ltd Marketing Support Division Suite 22, 41 Rawson Street Epping 2121, NSW Australia Tel: 61-2-9868-6733 Fax: 61-2-9868-6755 China - Beijing

Microchip Technology Consulting (Shanghai) Co., Ltd., Beijing Liaison Office Unit 915 Bei Hai Wan Tai Bldg. No. 6 Chaoyangmen Beidajie Beijing, 100027, No. China Tel: 86-10-85282100 Fax: 86-10-85282104

China - Chengdu

Microchip Technology Consulting (Shanghai) Co., Ltd., Chengdu Liaison Office Rm. 2401-2402, 24th Floor, Ming Xing Financial Tower No. 88 TIDU Street Chengdu 610016, China Tel: 86-28-86766200 Fax: 86-28-86766599

China - Fuzhou

Microchip Technology Consulting (Shanghai) Co., Ltd., Fuzhou Liaison Office Unit 28F, World Trade Plaza No. 71 Wusi Road Fuzhou 350001, China Tel: 86-591-7503506 Fax: 86-591-7503521

China - Hong Kong SAR

Microchip Technology Hongkong Ltd. Unit 901-6, Tower 2, Metroplaza 223 Hing Fong Road Kwai Fong, N.T., Hong Kong Tel: 852-2401-1200 Fax: 852-2401-3431

China - Shanghai

Microchip Technology Consulting (Shanghai) Co., Ltd. Room 701, Bldg. B Far East International Plaza No. 317 Xian Xia Road Shanghai, 200051 Tel: 86-21-6275-5700 Fax: 86-21-6275-5060 **China - Shenzhen**

Microchip Technology Consulting (Shanghai) Co., Ltd., Shenzhen Liaison Office Rm. 1812, 18/F, Building A, United Plaza No. 5022 Binhe Road, Futian District Shenzhen 518033, China Tel: 86-755-82901380 Fax: 86-755-8295-1393 **China - Qingdao** Rm. B505A, Fullhope Plaza, No. 12 Hong Kong Central Rd. Qingdao 266071, China Tel: 86-532-5027355 Fax: 86-532-5027205 **India**

Microchip Technology Inc. India Liaison Office Marketing Support Division Divyasree Chambers 1 Floor, Wing A (A3/A4) No. 11, O'Shaugnessey Road Bangalore, 560 025, India Tel: 91-80-2290061 Fax: 91-80-2290062 **Japan** Microchip Technology Japan K.K. Benex S-16F

Benex S-1 6F 3-18-20, Shinyokohama Kohoku-Ku, Yokohama-shi Kanagawa, 222-0033, Japan Tel: 81-45-471- 6166 Fax: 81-45-471-6122

Korea

Microchip Technology Korea 168-1, Youngbo Bldg. 3 Floor Samsung-Dong, Kangnam-Ku Seoul, Korea 135-882 Tel: 82-2-554-7200 Fax: 82-2-558-5932 or 82-2-558-5934 **Singapore** Microchip Technology Singapore Pte Ltd. 200 Middle Road

200 Middle Road #07-02 Prime Centre Singapore, 188980 Tel: 65-6334-8870 Fax: 65-6334-8850

Taiwan

Microchip Technology (Barbados) Inc., Taiwan Branch 11F-3, No. 207 Tung Hua North Road Taipei, 105, Taiwan Tel: 886-2-2717-7175 Fax: 886-2-2545-0139

EUROPE

Austria Microchip Technology Austria GmbH Durisolstrasse 2 A-4600 Wels Austria Tel: 43-7242-2244-399 Fax: 43-7242-2244-393 Denmark Microchip Technology Nordic ApS Regus Business Centre Lautrup hoj 1-3 Ballerup DK-2750 Denmark Tel: 45-4420-9895 Fax: 45-4420-9910 France Microchip Technology SARL Parc d'Activite du Moulin de Massy 43 Rue du Saule Trapu Batiment A - ler Etage 91300 Massy, France Tel: 33-1-69-53-63-20 Fax: 33-1-69-30-90-79 Germany Microchip Technology GmbH Steinheilstrasse 10 D-85737 Ismaning, Germany Tel: 49-89-627-144-0 Fax: 49-89-627-144-44 Italy Microchip Technology SRL Via Quasimodo, 12 20025 Legnano (MI) Milan, Italy Tel: 39-0331-742611 Fax: 39-0331-466781 Netherlands Microchip Technology Netherlands P. A. De Biesbosch 14 NL-5152 SC Drunen, Netherlands Tel: 31-416-690399 Fax: 31-416-690340 United Kingdom Microchip Ltd. 505 Eskdale Road Winnersh Triangle Wokingham Berkshire, England RG41 5TU Tel: 44-118-921-5869 Fax: 44-118-921-5820

07/10/03